

STPS5H100

Marking

S5H100

S5H100

DPAK

HIGH VOLTAGE POWER SCHOTTKY RECTIFIER

Table 2: Order Codes

Part Number

STPS5H100B

STPS5H100B-TR

Table 1: Main Product Characteristics

I _{F(AV)}	5 A
V _{RRM}	100 V
Тj	175°C
V _F (max)	0.61 V

FEATURES AND BENEFITS

- Negligible switching losses
- High junction temperature capability
- Low leakage current
- Good trade off between leakage current and forward voltage drop
- Avalanche specification

DESCRIPTION

High voltage Schottky barrier rectifier designed for high frequency miniature Switched Mode Power Supplies such as adaptators and on board DC to DC converters.

Table 3: Absolute Maximum (limiting values)



* : $\frac{dPtot}{dTj} > \frac{1}{Rth(j-a)}$ thermal runaway condition for a diode on its own heatsink

STPS5H100

Table 4: Thermal Parameters

Symbol	Parameter	Value	Unit
R _{th(j-c)}	Junction to case	2.5	°C/W

Table 5: Static Electrical Characteristics

Symbol	Parameter	Tests conditions		Min.	Тур	Max.	Unit
I _R * Reverse leakage current	Roverse leakage current	T _j = 25°C	V _R = V _{RRM}			3.5	μA
	T _j = 125°C	▼R – ▼RRM		1.3	4.5	mA	
V _F ** Forward voltage drop	T _j = 25°C	I _F = 5A			0.73	V	
	T _j = 125°C			0.57	0.61		
	Torward voltage drop	T _j = 25°C	I _F = 10A			0.85	v
		T _j = 125°C			0.66	0.71	

IF(av)(A)

 $\delta = tp/T$

20

40

6

5

4

3

2

1

0

Pulse test: * tp = 5 ms, δ < 2%

** tp = 380 μ s, δ < 2%

To evaluate the conduction losses use the following equation: $P = 0.51 \times I_{F(AV)} + 0.02 I_{F}^{2}(RMS)$

Figure 1: Average forward power dissipation versus average forward current



Rth(j-a)=80°C/W

60

Rth(j-a)=Rth(j-c)



Figure 3: Normalized avalanche power derating versus pulse duration



Figure 4: Normalized avalanche power derating versus junction temperature

Tamb(°C)

100

120

140

160

180

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80



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Figure 5: Non repetitive surge peak forward current versus overload duration (maximum values)



Figure 7: Reverse leakage current versus reverse voltage applied



Figure 9: Forward voltage drop versus forward current (maximum values)



Figure 6: Relative variation of thermal impedance junction to case versus pulse duration



Figure 8: Junction capacitance versus reverse voltage applied (typical values)



Figure 10: Thermal resistance junction to ambient versus copper surface under tab (Epoxy printed circuit board, copper thickness: 35µm)



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	DIMENSIONS				
REF.	REF. Millimete		ters Inc		
1	Min.	Max	Min.	Max.	
Α	2.20	2.40	0.086	0.094	
A1	0.90	1.10	0.035	0.043	
A2	0.03	0.23	0.001	0.009	
В	0.64	0.90	0.025	0.035	
B2	5.20	5.40	0.204	0.212	
С	0.45	0.60	0.017	0.023	
C2	0.48	0.60	0.018	0.023	
D	6.00	6.20	0.236	0.244	
Е	6.40	6.60	0.251	0.259	
G	4.40	4.60	0.173	0.181	
Н	9.35	10.10	0.368	0.397	
L2	0.80 typ.		0.031 typ.		
L4	0.60	1.00	0.023	0.039	
V2	0°	8°	0°	8°	

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Figure 12: Foot Print Dimensions (in millimeters)



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

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Table 6: Ordering Information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS5H100B	S5H100	DPAK	0.30 g	75	Tube
STPS5H100B-TR	S5H100		0.00 g	2500	Tape & reel

Cooling method: by conduction (C)

Table 7: Revision History

Date	Revision	Description of Changes
Jul-2003	6B	Last issue.
03-Nov-2005	7	DPAK Foot Print dimensions updated.
15-Feb-2006	8	ECOPACK statement added.

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